Uniaxial strain in graphene by Raman spectroscopy: G peak splitting, Grüneisen parameters, and sample orientation

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I. INTRODUCTION

Graphene is the two dimensional building block for carbon allotropes of every other dimensionality. Since its experimental discovery, graphene continues to attract enormous interest, in particular, as a new kind of matter, in which electron transport is governed by a Dirac-type wave equation, and as a model system for studying electronic and phonon phenomena, such as Kohn anomalies,17 and the breakdown of the Born-Oppenheimer approximation.9,10,18 In all these cases, experimental observations have successfully partnered with first-principles calculations, the latter providing additional microscopic insights and understanding, while being validated by the comparison with measurements. The Grüneisen parameters for the vibrational modes of graphite and graphene under biaxial strain were calculated by first principles, yielding excellent agreement with the thermomechanical properties of graphite.19 Recently, changes to the Raman spectra were reported due to the presence of stress in graphene.20–25 but the inferred strains disagreed by a factor of 5 or more for similar Raman shifts.20,22–24 Furthermore, no significant difference was seen between the cases of uniaxial and biaxial strain,20,23,24 in contrast with theory, and the opening of a band gap at the K point was suggested,20 again in contrast with the theory for small strains.26 It is thus necessary to conduct an accurate study in order to uncover the physics of strain for the graphene phonons.

Here, we apply uniaxial strain up to ~1.3% to a graphene monolayer, in typical steps of 0.05% (minimum of 0.01%; maximum of 0.25%) using two- and four-point bending setups (see Fig. 1) and compare this with first-principles calculations. The Raman spectra measured at each step are fully validated by the comparison with measurements. The Grüneisen parameters for the vibrational modes of graphite and graphene under biaxial strain were calculated by first principles, yielding excellent agreement with the thermomechanical properties of graphite.19 Recently, changes to the Raman spectra were reported due to the presence of stress in graphene.20–25 but the inferred strains disagreed by a factor of 5 or more for similar Raman shifts.20,22–24 Furthermore, no significant difference was seen between the cases of uniaxial and biaxial strain,20,23,24 in contrast with theory, and the opening of a band gap at the K point was suggested,20 again in contrast with the theory for small strains.26 It is thus necessary to conduct an accurate study in order to uncover the physics of strain for the graphene phonons.

II. EXPERIMENTAL

In order to controllably and reproducibly induce strain, graphene layers prepared by micromechanical cleavage of graphite are deposited on two different flexible substrates.
lowed to ensure reproducibility for both experiments. A total of 80 Raman spectra are measured for an average strain increment of 0.05%. The maximum strain applied to the sample is less than ~1.2%. In the two-point measurements, the spectra do not change until a nominal strain of ~0.55% is applied to the substrate. Afterward, they evolve linearly with strain. Thus, we assume this point as the reference zero strain for the sample. In the four-point measurement, the spectra evolve linearly from zero strain. The two sets of data are fully overlapping, further confirming the strain measurements. The data are fully reproducible over three strain cycles between maximum and minimum. Only when suddenly applying large strains or large strain increments we observed sample slippage indicated by an upshift, or smaller downshift, or no shift at all of the Raman parameters. Indeed, for samples suddenly bent to large strain values of a few percent, we often observed no change in the Raman peaks, indicating a general loss of contact between graphene and the substrate. It is thus extremely important to apply the strain in the most controlled way in order to ensure reproducibility and no slippage. A further set of 36 measurements is done for a fixed value of strain by rotating the incident polarization in 10° steps with respect to the strain axis and analyzing the scattered light in the plane parallel to the strain axis.

III. BACKGROUND

All carbons show common features in their Raman spectra in the 800–2000 cm\(^{-1}\) region, the so-called \(G\) and \(D\) peaks, which lie at around 1580 and 1350 cm\(^{-1}\), respectively. The \(G\) peak corresponds to the doubly degenerate \(E_g\) phonon at the Brillouin-zone center. The \(D\) peak is due to the breathing modes of \(sp^2\) rings and requires a defect for its activation.\(^{30,31}\) It comes from TO phonons around the \(K\) point of the Brillouin zone\(^{30,31}\) is active by double resonance (DR)\(^{32}\) and is strongly dispersive with excitation energy due to a Kohn anomaly at \(K\).\(^{17}\) The activation process for the \(D\) peak is an intervalley process as follows: (i) a laser-induced excitation of an electron/hole pair; (ii) electron-phonon scattering with an exchanged momentum \(\mathbf{q} \sim K\); (iii) defect scattering; and (iv) electron/hole recombination. The \(D\) peak intensity is not related to the number of graphene layers but only to the amount of disorder.\(^{30,31}\) DR can also happen as intravalley process, i.e., connecting two points belonging to the same cone around \(K\) (or \(K\')). This gives rise to the so-called \(D'\) peak, which can be seen around 1620 cm\(^{-1}\) in defected graphite. The 2D peak is the second order of the \(D\) peak. This is a single peak in monolayer graphene, whereas it splits in four bands in bilayer graphene, reflecting the evolution of the band structure.\(^{7}\) The \(2D'\) peak is the second order of the \(D'\) peak. Since 2D and 2D' peaks originate from a process where momentum conservation is obtained by the participation of two phonons with opposite wave vectors (\(q\) and \(\mathbf{q}^\prime\)), they do not require the presence of defects for their activation, and are thus always present. Indeed, high-quality graphene shows the \(G\), 2D, and 2D' peaks but not \(D\) and \(D'\).\(^{7}\)

IV. RESULTS AND DISCUSSION

A. Experimental trends

Figure 2 plots some representative Raman spectra as a function of strain. The strain is parallel to the longest side of
the substrate (Fig. 1) and is given by the ratio of substrate thickness to twice the radius of curvature. The spectra are fitted with lorentzians and Fig. 3 plots the resulting trends for the G and 2D peaks. Note that Figs. 3(a) and 3(b) are a combination of over 80 measurements on two samples, strained in two different experimental setups, and include a loading, unloading, and final loading cycle. Within the spectrometer resolution, we find no difference on prehistory and, for a single sample and cycle, the strain dependence is smooth. Linear fits using all the data yield \( \partial \omega G^0 / \partial \epsilon_t \approx -10.8 \text{ cm}^{-1}/\% \), \( \partial \omega G^- / \partial \epsilon_t \approx -31.7 \text{ cm}^{-1}/\% \), \( \partial \omega 2D / \partial \epsilon_t \approx -64 \text{ cm}^{-1}/\% \), and \( \partial \omega 2D / \partial \epsilon_t \approx -35 \text{ cm}^{-1}/\% \), where we call \( G^+ \) and \( G^- \) the higher and lower \( G \) subbands, by analogy with nanotubes.33,34

**B. Secular equation and Grüneisen parameters**

The observed behavior can be explained by considering the effect of uniaxial strain on the optical modes responsible for the \( G \), \( D \), and \( D' \) peaks, respectively. The Grüneisen parameter for the doubly degenerate in-plane Raman-active \( E_{2g} \) phonon, \( \gamma_{E_{2g}} \) is

\[
\gamma_{E_{2g}} = -\frac{1}{\omega_{E_{2g}}^0} \frac{\partial \omega_{E_{2g}}^h}{\partial \epsilon_t},
\]

where \( \epsilon_s = \epsilon_{lt} - \epsilon_{lt} \) is the hydrostatic component of the applied uniaxial strain, \( l \) is the longitudinal direction, parallel to the strain, and \( t \) is the direction transverse to it; \( \omega_{E_{2g}}^0 \) is the \( G \) peak position at zero strain. The shear deformation potential \( \beta_{E_{2g}} \) is defined as35,36

\[
\beta_{E_{2g}} = \frac{1}{\omega_{E_{2g}}^0} \frac{\partial \omega_{E_{2g}}^v}{\partial \epsilon_t},
\]

where \( \epsilon_s = \epsilon_{lt} - \epsilon_{lt} \) is the shear component of the strain.

Under uniaxial strain, the solution of the secular equation for the \( E_{2g} \) mode is35–38

\[
\Delta \omega_{E_{2g}}^\pm = \Delta \omega_{E_{2g}}^0 \pm \frac{1}{2} \Delta \omega_{E_{2g}}^v,
\]

\[
= -\omega_{E_{2g}}^0 \gamma_{E_{2g}} (\epsilon_{lt} + \epsilon_{lt}) \pm \frac{1}{2} \beta_{E_{2g}} \omega_{E_{2g}}^0 (\epsilon_{lt} - \epsilon_{lt}),
\]

where \( \Delta \omega_{E_{2g}}^0 \) is the shift resulting from the hydrostatic component of the strain, and \( \Delta \omega_{E_{2g}}^v \) is the mode splitting due to the shear component of the strain. \( \Delta \omega_{G^+} = \Delta \omega_{E_{2g}}^+ \) and \( \Delta \omega_{G^-} = \Delta \omega_{E_{2g}}^- \) are the shifts of the \( G^+ \) and \( G^- \) peaks relative to zero strain.

It is important to note that the resulting phonon eigenvectors are orthogonal:35–38 the \( E_{2g}^0 \) is perpendicular to the applied strain (and thus experiencing smaller softening) and the \( E_{2g}^0 \) parallel to it. This is analogous to the effect of curvature on the \( G \) peak of carbon nanotubes. The \( G \) peak splitting in nanotubes is the combined result of electron confinement and
curvature.\textsuperscript{33} Pure curvature splits the graphene $E_{2g}$ mode in a component parallel to the tube axis and one perpendicular. When the $sp^2$ bonds of graphene are deformed by rolling it in a tube, they lengthen and soften in the direction perpendicular to the axis, in order for the $\pi$, electrons to be perpendicular to it. This is proportional to curvature, so it is minimum parallel to the axis and maximum along the circumference, increasing with decreasing diameter.\textsuperscript{33,39} Thus, by curvature only, nanotubes will have a TO $G^+$ peak and a LO $G^*$, with the former softer than the latter, and more sensitive to diameter changes. This simple picture is reasonable for semiconducting nanotubes,\textsuperscript{33} while in metallic a further significant softening of the LO mode takes place due to the enhanced Kohn anomaly resulting from electron confinement.\textsuperscript{33} However, this further effect must be absent in “unrolled” tubes, i.e., graphene. Indeed, the full width at half maximum (FWHM) of the $G^+$ and $G^*$ peaks in graphene is roughly constant as a function of strain at $\sim12$ cm$^{-1}$, whereas FWHM($G^*$) in metallic nanotubes becomes much larger due to the increased electron-phonon coupling contribution.\textsuperscript{33}

By fitting the trends in Fig. 3 to Eqs. (1)–(3), we can experimentally determine the Grüneisen parameters for graphene. Under uniaxial strain\textsuperscript{6} $\varepsilon_{11}=\varepsilon$ and $\varepsilon_{22}=\nu \varepsilon$, where $\nu$ is the Poisson’s ratio. If one could strain free-hanging graphene samples, the Poisson’s ratio for graphene itself should be used. This can be taken as the in-plane Poisson’s ratio of graphite $\sim0.13$.\textsuperscript{40} However, the lack of loading-unloading hysteresis for our results implies good adhesion between graphene and our substrates for the whole range of applied strains. SU8 is a transversely isotropic material with a 0.33 in-plane Poisson’s ratio.\textsuperscript{37} PET and spandex have also Poisson’s ratios between 0.3–0.35. We thus use $\nu=0.33$. This corresponds to the case of ideal contact between graphene and substrate. Equation (3) is now rewritten as

$$\Delta \omega_{E_{2g}}^{E_{2g}} = -\omega_{E_{2g}}^{E_{2g}} \gamma_{E_{2g}} (1 - \nu) \varepsilon \pm \frac{1}{2} \beta_{E_{2g}} \omega_{E_{2g}}^{E_{2g}} (1 + \nu) \varepsilon,$$

yielding

$$\gamma_{E_{2g}} = -\frac{\Delta \omega_{G^+} + \Delta \omega_{G^-}}{2 \omega_{G^0} (1 - \nu) \varepsilon},$$

$$\beta_{E_{2g}} = \frac{\Delta \omega_{G^+} - \Delta \omega_{G^-}}{\omega_{G^0} (1 + \nu) \varepsilon}.$$  

From the data in Fig. 3(a), we get $\gamma_{E_{2g}}=1.99$ and $\beta_{E_{2g}}=0.99$. These experimental parameters can now be used to estimate the trends for free-hanging graphene under uniaxial strain. Inserting $\gamma_{E_{2g}}=1.99$, $\beta_{E_{2g}}=0.99$, and $\nu=0.13$ in Eq. (4), we get $\partial \omega_{G^+}/\partial \varepsilon \sim -18.6$ cm$^{-1}$/% and $\partial \omega_{G^-}/\partial \varepsilon \sim -36.4$ cm$^{-1}$/%. Note that the effect of the substrate higher Poisson’s ratio is to significantly decrease the slope of the $G^+$ peak. These results are also in excellent agreement with our first-principles calculations (see later).

We can now use our fitted $\gamma_{E_{2g}}$ to deduce the expected peak variations for graphene under biaxial strain. In this case $\varepsilon_{11}=\varepsilon_{22}=\varepsilon$ and, from Eq. (3), $\Delta \omega_{E_{2g}}=-2 \omega_{E_{2g}}^{E_{2g}} \gamma_{E_{2g}} \varepsilon$, since the shear deformation term cancels. This means, as expected, that the $G$ peak does not split. Also, no difference is expected between free-hanging graphene and graphene on a substrate. Thus, for biaxial strain, $\partial \omega_{G^+}/\partial \varepsilon \sim -63$ cm$^{-1}$/%.

To the best of our knowledge, no data exist in literature for uniaxial strain on graphite. However, several authors applied hydrostatic pressure on graphite\textsuperscript{41–43} finding $\partial \omega_{G^+}/\partial \sigma_{h} \sim 4.4–4.8$ cm$^{-1}$/GPa, where $\sigma_{h}$ is the hydrostatic pressure (stress). The in-plane biaxial strain under hydrostatic pressure is $\varepsilon=(\sigma_{h}+\sigma_{h})/2$. Since for graphite in-plane $\sigma_{h} \sim 1/1250$ GPa,\textsuperscript{40} the data in Refs. 41–43 correspond to an in-plane Grüneisen parameter $\gamma_{E_{2g}} \sim 1.72–1.90$, in very good agreement with our results. Many groups have considered hydrostatic pressure on nanotubes (see, e.g., Refs. 35, 36, and 43). Generally it is found $\partial \omega_{G^+}/\partial \sigma_{h} \sim 4–5$ cm$^{-1}$/GPa, in good agreement with graphene and graphite. However, electron confinement and other effects in nanotubes warrant a more detailed comparison of our results on graphene with the trends for the individual LO and TO $G$ bands in nanotubes, which will be the subject of further investigation.

Several experiments exist for uniaxial strain on graphite fibers.\textsuperscript{44} These could be the best approximation of uniaxial strain along the graphite plane, since their very large diameter compared to single-wall nanotubes ensures other possible effects due to electron confinement will be negligible.\textsuperscript{33} Extensive work on carbon fibers of different moduli has shown that the peaks’ shift is directly related to axial stress, rather than strain.\textsuperscript{45} Thus, one can assume that in uniaxial experiments, the applied stress is the known parameter, and the strain applied to the atomic bonds can be derived from $\varepsilon_{11}=S_{hi}\sigma_{h}$, where $S_{hi}=1/E$ is the fiber elastic compliance, $E$ is the Young’s modulus and $\sigma_{h}$ is the applied longitudinal stress. Therefore, in order to correctly estimate the strain, it is necessary to know the fiber $E$, which, in general, is significantly lower than the in-plane Young’s modulus of graphite.\textsuperscript{44} Then, if we extend the universal relation between Raman peak shift and uniaxial stress to graphene, the following should hold: $\frac{\partial \omega_{G^+}}{\partial \sigma_{h}} \sim \frac{E_{G^+} \gamma_{G^+}}{\omega_{G^0}} \varepsilon_{11}$. Most fibers show a uniaxial stress sensitivity of $\partial \omega_{G^+}/\partial \sigma_{h} \sim 2–3$ cm$^{-1}$/GPa.\textsuperscript{44} In particular, polyacrylonitrile (PAN)-based carbon fibers with “onion skin” morphology (i.e., those most similar to large multwall nanotubes) have $\partial \omega_{G^+}/\partial \sigma_{h} \sim 2.3$ cm$^{-1}$/GPa.\textsuperscript{44} Note that, due to disorder, the $G$ peak of carbon fibers is very broad and not resolved in two subbands. Thus, the fitted $G$ represents the average shift of the two subbands. Our average shift, using the in-plane graphite Poisson’s ratio, as needed in order to compare with fibers, is $\partial \omega_{G^+}/\partial \varepsilon \sim -27$ cm$^{-1}$/%. If we scale the uniaxial strain sensitivity of PAN fibers by the in-plane Young’s modulus of graphite $\sim1090$ GPa,\textsuperscript{40} this would imply a value of $\sim-25$ cm$^{-1}$/%, in excellent agreement with our average value. This also validates the assumption that the graphene Young’s modulus is similar to the in-plane Young’s modulus of graphite, in agreement with recent measurements.\textsuperscript{46} A notable discrepancy exists only with Ref. 38 for uniaxial measurements on fibers. However, their data imply $\gamma_{G} \sim 2.87$, in disagreement with both our measurements and with all graphite literature.\textsuperscript{41–44} We also note that our results disagree with recent Raman experiments on
uniaxial strain in graphene,\textsuperscript{20,24} which report much smaller $\partial \omega / \partial \varepsilon$, implying much smaller Grüneisen parameter. It is difficult to see how the Grüneisen parameter of graphene should be much smaller than that measured in plane for graphite. Moreover, no $G$ peak splitting was observed for uniaxial strain,\textsuperscript{20,24} again in contrast with both our observation and general expectations.

We now consider the singly degenerate modes corresponding to the $D$ and $D'$ peaks. The $D$ peak is a breathing mode similar to the TO $A_{1g}$ phonon at $K$.\textsuperscript{47} For pure $A_{1g}$ symmetry and small strains, the uniaxial shift $\Delta \omega_{A_{1g}}$ is given only by the hydrostatic component of the stress

$$\Delta \omega_{A_{1g}} = - \omega_{A_{1g}} \gamma_{A_{1g}} (\varepsilon_u + \varepsilon_d).$$

On the other hand, the $D'$ phonon has $E$ symmetry\textsuperscript{47} and we could expect in principle splitting and a relation similar to Eq. (4). However, experimentally this peak is very weak and we cannot resolve any splitting in the strain range we have considered. Thus, for small strains, we write for both Raman peaks

$$\Delta \omega_{2D,2D'} = - \omega_{2D,2D'} \gamma_{2D,2D'} (1 - \nu) \varepsilon.$$

Combining our data with Eq. (8), we get $\gamma_D \sim 3.55$ and $\gamma_{D'} \sim 1.61$. For free-hanging graphene, these give $\partial \omega_{2D}/\partial \varepsilon \sim -83$ cm\textsuperscript{-1}/\% and $\partial \omega_{2D}/\partial \varepsilon \sim -45$ cm\textsuperscript{-1}/\%. In the case of graphene under biaxial strain, $\varepsilon_{uu} = \varepsilon_{dd} = \varepsilon$ and $\Delta \omega_{2D,2D'} = -2 \omega_{2D,2D} \gamma_{2D,2D'}$. Thus, using our fitted Grüneisen parameters, the expected 2D and 2D' variation as a function of biaxial strain are $\partial \omega_{2D}/\partial \varepsilon \sim -191$ cm\textsuperscript{-1}/\% and $\partial \omega_{2D}/\partial \varepsilon \sim -104$ cm\textsuperscript{-1}/\%.

To the best of our knowledge, no data exist for the 2D- or 2D'-peak dependence in graphite as a function of uniaxial strain. However, Ref. 44 measured $\partial \omega_{2D}/\partial \sigma_{tt} \sim 6.4$ cm\textsuperscript{-1}/GPa for PAN carbon fibers. This scales to $\partial \omega_{2D}/\partial \varepsilon \sim -70$ cm\textsuperscript{-1}/GPa in graphene, in agreement with our predicted uniaxial trend, when using the in-plane Poisson’s ratio of graphite to compare with fibers. For graphite under hydrostatic pressure, Ref. 48 reported $\partial \omega_{2D}/\partial \sigma_{tt} \sim 12.3$ cm\textsuperscript{-1}/GPa and $\partial \omega_{2D}/\partial \sigma_{tt} \sim 9$ cm\textsuperscript{-1}/GPa. This corresponds to an in-plane biaxial strain $\varepsilon = (S_{tt} + S_{dd}) \sigma_{tt}$. From $1/(S_{tt} + S_{dd}) \sim 1/1250$ GPa,\textsuperscript{40} we get $\partial \omega_{2D}/\partial \varepsilon \sim -154$ cm\textsuperscript{-1}/\%, $\gamma_{2D} = 2.84$, $\partial \omega_{2D}/\partial \varepsilon \sim -113$ cm\textsuperscript{-1}/\%, and $\gamma_{2D} = 1.74$, in broad agreement with our predictions for biaxial strain.

Finally, we note that, in all cases, the 2D peak is extremely sensitive to strain. With a typical spectrometer resolution of $\sim 2$ cm\textsuperscript{-1}, a remarkable sensitivity of $\sim 0.01$% and 0.03% can be achieved for biaxial and uniaxial strains, respectively. We also note that a combined analysis of $G$ and 2D FWHM and shifts should allow to distinguish between effects of strain, doping, or disorder.\textsuperscript{9-11}

\begin{figure}[h]
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\includegraphics[width=0.5\textwidth]{Graph.png}
\caption{(Color online) Eigenvectors of $G^+$ and $G^-$ modes determined by density-functional perturbation theory. These are perpendicular to each other, with $G^+$ polarized along the strain axis, as expected.}
\end{figure}

C. First-principles calculations

To further understand our findings, we perform first-principles calculations on free-standing graphene, for small strains up to $\sim 1\%$, to compare with experiments. The effects on electron and phonon bands of larger strains will be reported elsewhere. We use density-functional theory and density-functional perturbation theory\textsuperscript{49} as implemented in the PWSCF package of the QUANTUM-ESPRESSO distribution,\textsuperscript{50} with local-density approximation, with norm-conserving pseudopotentials\textsuperscript{51} and a plane-wave expansion up to 55 Ry cutoff. The Brillouin zone is sampled on 42 $\times$ 42 $\times$ 1 Monkhorst-Pack mesh with a cold smearing in the electronic occupations of 0.02 Ry. We use the equilibrium lattice parameter $a=2.43$ Å and an interlayer spacing of 15 Å. We apply the strain in different directions. For each direction and strain, we determine the structure with the lowest total energy by varying the size of the unit cell in the direction perpendicular to the strain. At zero strain, $\omega_{100} = 1603.7$ cm\textsuperscript{-1}, $\omega_{110} = 1326$ cm\textsuperscript{-1}, and $\nu=0.15$. Figure 4 plots the resulting $G^+/G^-$ eigenvectors. These are perpendicular to each other with the $G^-$ eigenvector oriented along the strain direction as expected. For small strains, we find $\partial \omega_{G}/\partial \varepsilon \sim -34$ cm\textsuperscript{-1}/\% and $\partial \omega_{G}/\partial \varepsilon \sim -17$ cm\textsuperscript{-1}/\%, independent on the strain direction, as expected from symmetry. We also get $\gamma_{G} = 1.87$ and $\beta_{E_{2g}} = 0.92$, in excellent agreement with our measured parameters. Note that in order to compare the calculated trends for $G^+$ and $G^-$ with our measurements, we need to insert the theoretical parameters in Eq. (4) together with the substrate Poisson’s ratio. This gives $\partial \omega_{G}/\partial \varepsilon \sim -30$ cm\textsuperscript{-1}/\% and $\partial \omega_{G}/\partial \varepsilon \sim -10.3$ cm\textsuperscript{-1}/\%, in excellent agreement with the fits in Fig. 3(a). We also calculate the biaxial strain variation for the $G$ peak. We find $\partial \omega_{G}/\partial \varepsilon \sim -58$ cm\textsuperscript{-1}/\% and $\gamma_{E_{2g}} = 1.8$, again in excellent agreement with the biaxial values based on our experimental Grüneisen parameter.

We then calculate the uniaxial and biaxial strain variation for the 2D peak. We find $\partial \omega_{2D}/\partial \varepsilon \sim -60$ cm\textsuperscript{-1}/\% for uniaxial, and $\partial \omega_{2D}/\partial \varepsilon \sim -144$ cm\textsuperscript{-1}/\% for biaxial and $\gamma_{2D} \sim 2.7$ for both. These are in excellent agreement with the results of hydrostatic pressure experiments on graphite, and in broad agreement with our experimental data for uniaxial strain (and the consequent biaxial predictions), being $\sim 25/\%$ smaller. It is important to consider that, while for the Raman-active $G$ mode we are probing the same center-zone phonon when measuring the Raman spectrum on a strained sample, the Raman $D$ and $D'$ peaks are zone-boundary phonons activated by double resonance. Any change in the double-resonance condition during the strain experiments
will vary the actual phonon probed in the Raman measurements, as well as inducing a change in the phonon frequencies. Thus, the relationship between phonon Grüneisen parameters and the variation in the Raman peaks with applied strain is, in principle, more complex than the case of the $G$ peak and what implied by Eqs. (7) and (8). Indeed, while biaxial strain does not move the relative positions of the Dirac cones, uniaxial strain changes them. Note that this does not open any gap, in contrast with the conclusions of Ref. 20. Still, it can have a significant influence in the double-resonance process. While the $D'$ is intravalley, i.e., connecting two points belonging to the same cone around $K$ or $K'$, the $D$ peak phonon requires scattering from the cone around $K$ to that around $K'$. Thus, its wave vector is determined by the relative distance of the Dirac cones and by the laser excitation energy. Our experiments are performed for a fixed excitation. Then, what we measure in Raman spectroscopy of uniaxially strained graphene is the combination of the 2D phonon shift due to strain and a possible additional shift due to the fact that the relative movement of the Dirac cones changes the phonon wave vector. For an asymmetric movement, this could lead to peak broadening and splitting. Indeed the experimental FWHM (2D) significantly increases with strain. In the case of the 2D libraries, the movement of the relative positions of the cones will have no consequence since it is an intravalley process. However, for both $D$ and $D'$, other effects could be given by the renormalization of Fermi velocity and phonon-group velocity with strain. Thus, especially for the $D$ peak, our measured $\gamma_D$ has to be taken as an upper boundary, and a more general expression to evaluate it can be $\gamma_D = \frac{\omega_D - \Delta_D}{\omega_D}$, with $\Delta_D$ encompassing corrections due to the changes in the phonon selected in double resonance, as a function of strain. We note that in the case of biaxial strain, at least the effects due to the relative movement of the Dirac cones are absent. Then, Raman experiments on graphene under biaxial strain would be more suited to measure the $D$ mode Grüneisen parameter, and this explains why our calculations are in excellent agreement with the hydrostatic pressure experiments on graphite. Thus, given the peculiar nature of electron-phonon and electron-electron interactions around the $K$ point in graphene, combined with the relative movement of the $K$ and $K'$ points under uniaxial strain, and the possible renormalizations of electron and phonon bands, the full theoretical description of the 2D peak under uniaxial strain still needs further investigation.

D. Crystallographic orientation

We now consider the polarization dependence of the $G^*$ and $G'$ intensities expected due to the nature of the phonon eigenvectors and their orientation with respect to the strain. The effective photon-phonon interaction Hamiltonian for the $E_{2g}$ phonons is

$$H_{\text{int}} \approx \left[ \xi_x^\text{in} \xi_x^\text{out} - \xi_y^\text{in} \xi_y^\text{out} \right] u_x - \left[ \xi_x^\text{in} \xi_y^\text{out} + \xi_y^\text{in} \xi_x^\text{out} \right] u_y. \quad (9)$$

Here $\xi_x^\text{in(out)}$ are the Cartesian components of the electric field of the incident (scattered) light and $u_x,u_y$ are the phonon displacements in the $(x,y)$ basis (see Fig. 5 for details). The $x$ axis is chosen perpendicular to the C-C bond. This Hamiltonian is the only allowed by the $C_{6v}$ symmetry of graphene. In the presence of strain, the Hamiltonian changes but the correction will be on the order of the strain itself. For a fixed small strain, these corrections can be ignored, in first approximation, in the calculation of the polarization dependence of the $G$ bands. The main effect of strain is to force the phonon normal modes to be longitudinal ($u_l$) and transverse ($u_t$) with respect to the strain axis, as discussed above, and shown in Fig. 4. If we call $\varphi$, the angle between the strain axis and the $x$ axis, we can write

$$u_x = u_l \cos \varphi + u_t \sin \varphi, \quad u_y = -u_l \sin \varphi + u_t \cos \varphi. \quad (10)$$

In our Raman spectrometer, we can excite with linearly polarized light and use an analyzer for the scattered radiation. This means that the corresponding electric-field vectors have definite orientations $\mathbf{E}_{\text{in(out)}} = \xi_{x(y)} \sin \varphi \cos \varphi_{\text{in(out)}}$, where the polarization is measured with respect to the strain axis. Substituting these in Eq. (9), the matrix elements corresponding to the emission of longitudinal and transverse phonons are proportional to $-\sin(\theta_{\text{in}} + \theta_{\text{out}} + 3\varphi)$ and $\cos(\theta_{\text{in}} + \theta_{\text{out}} + 3\varphi)$, respectively. The intensities of the two peaks are given by their squares

$$I_{G'} \propto \sin^2(\theta_{\text{in}} + \theta_{\text{out}} + 3\varphi), \quad I_{G^*} \propto \cos^2(\theta_{\text{in}} + \theta_{\text{out}} + 3\varphi). \quad (11)$$

To test this, we do polarization measurements with an analyzer for scattered light aligned with the strain direction ($\theta_{\text{out}}=0$) and rotating the incident polarization with respect to the strain axis in steps of $10^\circ$ (Fig. 6). The data in Fig. 6 are well fitted by $I_{G'} \propto \sin^2(\theta_{\text{in}} + 34^\circ)$ and $I_{G^*} \propto \cos^2(\theta_{\text{in}} + 34^\circ)$. According to Eq. (11), this gives $\varphi = 11.3^\circ$. We thus get the orientation of the graphene crystal with respect to the known strain axis.

The physical origin of the polarization dependence of the $G^*/G'$ peaks can be traced to the microscopic mechanism of Raman scattering. The light interaction with graphene phonons is mediated by electrons. As discussed in Ref. 53.
for unstrained graphene, if one assumes the electron spectrum to be isotropic (Dirac), the $G$ peak intensity vanishes. Thus, the $G$ peak is entirely due to the anisotropic terms in the electronic spectrum. In other words, in order to contribute to the $G$ peak, electrons must “feel” the crystallographic directions. In unstrained graphene, this has no consequence since the two vibrations are degenerate and not resolved. Under strain, the two subbands correspond to definite orientations of the vibrations with respect to the strain axis. It is thus the interaction of electrons, which feel the crystallographic directions, with phonons entirely determined by the strain direction that gives the polarization dependence.

V. CONCLUSIONS

In summary, we probed with Raman spectroscopy the optical phonons of graphene as a function of uniaxial strain. We find that the doubly degenerate $E_{2g}$ mode splits in two components: one polarized along the strain, the other perpendicular. This split of the Raman $G$ peak in two subbands $G^+$ and $G^-$ is analogous to that induced by curvature in nanotubes. These subbands redshift with increasing strain, while their splitting increases, in excellent agreement with first-principles calculations. Their relative intensities vary with polarization, allowing to probe the sample crystallographic orientation with respect to the strain. The 2D and 2D$^*$ bands downshift but do not split for small strains. Our results can be used to quantify the amount of uniaxial or biaxial strain, providing a fundamental tool for graphene-based nanoelectronics and nano/microelectro mechanical systems.

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